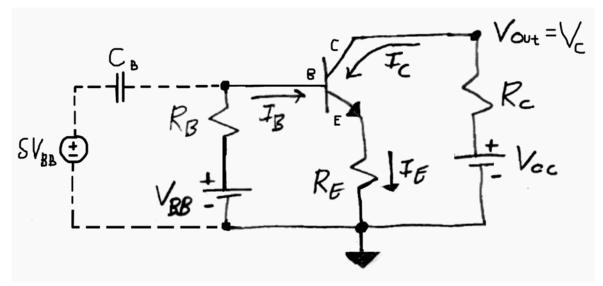
Physics 120 - David Kleinfeld - Spring 2015

Notes on common emitter transistor amplifier (accompanies Laboratory 8).

Here we use the transistor as a voltage amplifier. The idea is to turn a voltage at the input into a current through the base (B), and then turn the current flow through the transistor, *i.e.*, collector (C) to emitter (E) into a voltage drop. Since the dependent current source $I_C = \beta I_B$ can attain any voltage drop, the output is taken at the collector.

Our initial focus is on the DC properties, *i.e.*, setting up the bias to keep the transistor in the roughly "centered" in the active region. As an important technical aside, we use a nonzero value of R_E so that variations in the value of β can be removed to first approximation.



The left hand loop

$$-V_{BB} + I_{B}R_{B} + V_{BE} + I_{E}R_{E} = 0$$

but
$$I_{B} = \frac{1}{\beta}I_{c} \text{ and } I_{E} = \frac{1+\beta}{\beta}I_{C}$$

so $I_{\rm c} = \frac{\beta}{1+\beta} \frac{V_{\rm BB} - V_{\rm BE}}{R_{\rm c} + R_{\rm B}/(1+\beta)}.$

Recall that $\beta >>1$ ($\beta \sim 200$ in this exercise) and choose R_B << (1+ β)R_E. Then

$$I_{c} \simeq \frac{V_{_{BB}} - V_{_{BE}}}{R_{_{E}}}$$

The right hand loop

$$-V_{cc} + I_{c}R_{c} + V_{cE} + I_{E}R_{E} = 0$$

but
$$I_{E} = \frac{1+\beta}{\beta}I_{c} \simeq I_{c}$$

so
$$I_c \simeq \frac{V_{cc} - V_{cE}}{R_E + R_c}$$

This equation defines the "load line" for the transistor, *i.e.*, the relation between I_C and V_{CE} that must be satisfied in addition to the intrinsic relation between I_C and V_{CE} that results from the transistor properties.

The output voltage is given by $V_c = V_{cE} + I_E R_E$. Thus

$$\begin{split} V_{c} &\simeq V_{cc} - I_{c} \left(R_{E} + R_{c} \right) + I_{c} R_{E} \\ &= V_{cc} - I_{c} R_{c} \\ &= V_{cc} - \frac{V_{BB} - V_{BE}}{R_{E}} R_{c} \\ &= \left(V_{cc} + \frac{R_{c}}{R_{E}} V_{BE} \right) - \frac{R_{c}}{R_{E}} V_{BB} \end{split}$$

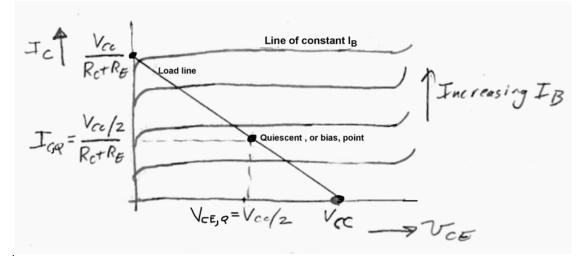
The term in the brackets is just a constant. The term proportional to V_{BB} contains a potential signal term. That is, if we change the base voltage source, such as by addition an AC current to the base through the inclusion of a time varying signals δV_{BB} (see previous figure), there is a corresponding change in the voltage at the collector, *i.e.*,

$$\delta V_{_{\mathrm{C}}} \simeq - \frac{\mathsf{R}_{_{\mathrm{C}}}}{\mathsf{R}_{_{\mathrm{E}}}} \delta V_{_{\mathrm{BB}}}$$

The ratio "- R_c / R_E" is the voltage gain. The minus means that the signal is inverted. Notice how β does not play a role (so long as $\beta >>1$)! This is the hallmark of good design - factor out the exact value of the gain since this is large but variable from device to device.

Load line and set point

The set-point are the values of I_C and V_{CE} , denoted $I_{C,Q}$ and $V_{CE,Q}$, in the absence of AC input. We plot the load line equation (above) on top of the I_C versus V_{CE} curves for this transistor (see attached sheet for a small part of the measured relation) to establish the set-point.



The value of V_{CE} is bounded at the low end by the cut-off voltage of 0.2 V. From the load line equation $I_c \simeq \frac{V_{CC} - V_{CE}}{R_E + R_c}$, we see that V_{CE} is bounded from above to be V_{CC} (typically many Volts). Since V_{CC} >> 0.2 V, we choose V_{CEQ =} V_{CC}/2 to insure a (near) maximum voltage swing.

Selecting values

Choose the gain. For |Gain| = 10, $R_C = 10 R_E$. Satisfy $R_B << \beta R_E$. Since $\beta \ge 100$, select $R_B = 10 R_E$. Pick V_{CQ} . We choose $V_{CQ} = 7.5 V$. Then $V_{CC} = 2 V_{CEQ} = 15V$. Pick I_{CQ} . We choose $I_{CQ} = 1 \text{ mA}$.

Satisfy the load-line relation $I_{_{CQ}} \simeq \frac{V_{_{CC}} - V_{_{CEQ}}}{R_{_E} + R_{_C}} \simeq \frac{V_{_{CC}}}{2R_{_C}}$ which yields $R_{_C} \simeq \frac{V_{_{CC}}}{2I_{_{CQ}}}$.

Picking standard values of resistors gives:

$$R_{c} \simeq \frac{15V}{2mA} \sim 6.8 \text{ k}\Omega,$$
$$R_{E} \simeq \frac{R_{c}}{10} \sim 680 \Omega,$$

and

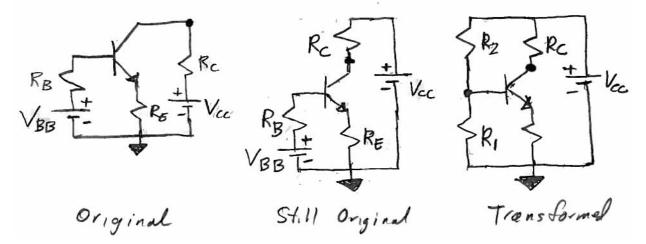
$$R_{\rm B} \simeq 10 R_{\rm F} \sim 6.8 \ \rm k\Omega$$

Lastly,

$$V_{_{BB}} \simeq v_{_{BE}} + I_{_{E}}R_{_{E}} \sim 1.5 \text{ V}.$$

Convert from dual to single power supply

Rather than have two batteries, we use one battery for both V_{BB} and V_{CC} . Since V_{CC} is the larger voltage, we use it as the supply. and build a voltage divider to replace V_{BB} and R_B .



From the diagrams above,

$$\mathbf{R}_{\mathbf{B}} \simeq \frac{\mathbf{R}_{1}\mathbf{R}_{2}}{\mathbf{R}_{1} + \mathbf{R}_{2}} \qquad \qquad \mathbf{V}_{\mathbf{B}\mathbf{B}} \simeq \frac{\mathbf{R}_{1}}{\mathbf{R}_{1} + \mathbf{R}_{2}} \mathbf{V}_{\mathbf{C}\mathbf{C}}$$

so that

$$\mathsf{R}_{_{1}} \simeq \mathsf{R}_{_{B}} \frac{\mathsf{V}_{_{CC}}}{\mathsf{V}_{_{CC}} - \mathsf{V}_{_{BB}}} \quad \text{and} \quad \mathsf{R}_{_{2}} \simeq \mathsf{R}_{_{B}} \frac{\mathsf{V}_{_{CC}}}{\mathsf{V}_{_{BB}}}.$$

Substituting in values and using standard components gives:

$$\mathsf{R}_{1} \simeq 5.6 \,\mathsf{k}\Omega \frac{15 \,\mathsf{V}}{15 \,\mathsf{V} - 1.5 \,\mathsf{V}} \sim 5.6 \,\mathsf{k}\Omega \qquad \text{and} \qquad \mathsf{R}_{2} \simeq 5.6 \,\mathsf{k}\Omega \frac{15 \,\mathsf{V}}{1.5 \,\mathsf{V}} \sim 56 \,\mathsf{k}\Omega$$

Lastly, must also satisfy $R_1 \ll R_{in}$, *i.e.*, $R_1 \ll \beta R_E$, so that the input resistance does not contribute to the voltage divider. Our choises lead to self-consistency with 5.6k $\Omega \ll 200x680\Omega$ or 5.6k $\Omega \ll 140k\Omega$, so all is fine.

Coupling of the AC signal, δV_{BB} .

This signal is high pass filtered with a cut-on frequency of $1/(2\pi R_B C_B)$. The desired cut-on frequency, f_C , sets the value of C_B , by $C_B = 1/(2\pi f_C R_B)$.

Fini!